



AMP1030 SOLID STATE HIGH POWER AMPLIFIER

FEATURES

Class AB linear LDMOS design
 Instantaneous wide bandwidth
 Suitable for all modulations standards
 Built-in protection circuits
 High reliability and ruggedness

ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	20 - 1000 MHz	
Power Output Psat	125 Watt Min	CW
Power Gain	52 dB Min	
Gain Flatness	3.0 dB p-p Max	Constant input power
Input Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	>30 dBc Typ	39dBm/Tone, $\Delta = 1\text{MHz}$
Harmonics	>20dBc Typ	At rated Pout
Non Harmonics Spurious	>60 dBc Min	
Operating Voltage	28 - 30 VDC	
Current Consumption	13 Amp Max	At rated Pout
Max Input Power	+8 dBm	Without damage
Load VSWR Protection	$\infty : 1$	
Turn On / Off Speed	5 μSec Max	

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Case Temperature	-20 to +75 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non Condensation

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions	162 X 86 X 27 mm	Excluding Connectors
Weight	600 gr.	Typical Weight
RF Connectors In/Out	SMA female	
DC Power / Interface Connector	9-Pin Dsub	
Cooling	External Heatsink	Forced air required

D-SUB CONNECTOR PIN ASSIGNMENT

Pin	Function	Description
1	FWD	N/C
2	REV	N/C
3	CURRENT SENSOR	$I_D @ 20\text{mV}/100\text{mA}$ Typ
4	TEMP SENSOR	$V_T @ 10\text{mV}/^\circ\text{C} + 500\text{mV}$ Typ
5	SHUTDOWN	TTL
6, 7	VDD	28VDC
8, 9	GND	Ground

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OUTLINE DRAWING

